O V, 500 IIIA PNP resistor-equipped transistor

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTD113ZU

2. Features and benefits

- 500 mA output current capability
- · Reduces pick and place costs
- · Built-in bias resistors
- ±10 % resistor ratio tolerance
- Simplifies circuit design
- · Reduces component count
- High temperature applications up to 175 °C
- AEC-Q101 qualified

3. Applications

- Cost-saving alternative for BC807 series in digital applications
- Control of IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---------------------------|--------------------------|-----|-----|------|------|
| V _{CEO} | collector-emitter voltage | open base | - | - | -50 | V |
| Io | output current | | - | - | -500 | mA |
| R1 | bias resistor 1 (input) | T _{amb} = 25 °C | 0.7 | 1 | 1.3 | kΩ |
| R2/R1 | bias resistor ratio | | 9 | 10 | 11 | |



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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|--------------------|--------------------|-----------------------------------|
| 1 | I | input (base) | <u></u> 3 | |
| 2 | G | GND (emitter) | | O O O O O O O O O |
| 3 | 0 | output (collector) | SC-70 (SOT323) | R2 GND sym003 |

6. Ordering information

Table 3. Ordering information

| Type number Package | | | | | | | |
|---------------------|-------|--|---------|--|--|--|--|
| | Name | Description | Version | | | | |
| PDTB113ZU | SC-70 | plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body | SOT323 | | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PDTB113ZU | ZH% |

[1] % = placeholder for manufacturing site code

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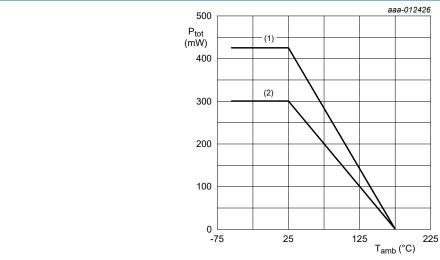
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|--------------------------|-----|-----|------|------|
| V _{CBO} | collector-base voltage | open emitter | | - | -50 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -50 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| VI | input voltage | | | -10 | 5 | V |
| Io | output current | | | - | -500 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 300 | mW |
| | | T _{amb} ≤ 25 °C | [2] | - | 425 | mW |
| Tj | junction temperature | | | - | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -55 | 175 | °C |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



- (1) FR4 PCB, 4-layer copper, standard footprint
- (2) FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 1. Power derating curves

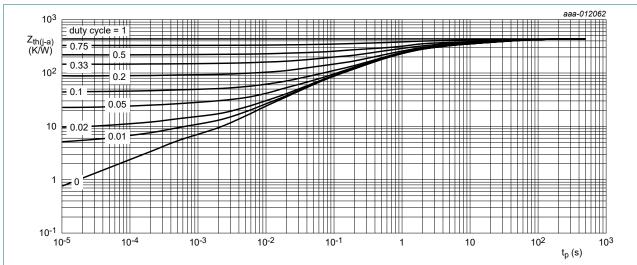
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9. Thermal characteristics

Table 6. Thermal characteristics

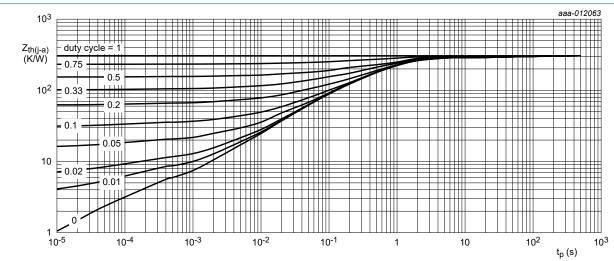
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------|-------------------------|-------------|-----|-----|-----|-----|------|
| uily-a) | thermal resistance from | in free air | [1] | - | - | 500 | K/W |
| | junction to ambient | | [2] | - | - | 353 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT323/SC-70; typical values



FR4 PCB, 4-layer copper, tin-plated and standard footprint.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT323/SC-70; typical values

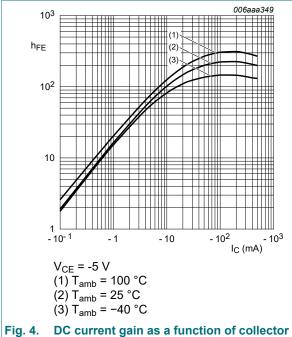
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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|--|-----|------|------|------|------|
| I _{CBO} | collector-base cut-off | V _{CB} = -40 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | -100 | nA |
| | current | V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | -100 | nA |
| I _{CEO} | collector-emitter cut-off current | V _{CE} = -50 V; I _B = 0 A; T _{amb} = 25 °C | | - | - | -0.5 | μA |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C | | - | - | -0.8 | mA |
| h _{FE} | DC current gain | V_{CE} = -5 V; I_{C} = -50 mA; T_{amb} = 25 °C | | 70 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | I_C = -50 mA; I_B = -2.5 mA; T_{amb} = 25 °C | | - | - | -100 | mV |
| $V_{I(off)}$ | off-state input voltage | V _{CE} = -5 V; I _C = -100 μA; T _{amb} = 25 °C | | -0.3 | -0.6 | -1 | V |
| V _{I(on)} | on-state input voltage | V_{CE} = -0.3 V; I_{C} = -20 mA; T_{amb} = 25 °C | | -0.4 | -0.8 | -1.4 | V |
| R1 | bias resistor 1 (input) | T _{amb} = 25 °C | | 0.7 | 1 | 1.3 | kΩ |
| R2/R1 | bias resistor ratio | | | 9 | 10 | 11 | |
| C _c | collector capacitance | V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C | | - | 11 | - | pF |
| f _T | transition frequency | V_{CE} = -5 V; I_{C} = -50 mA; f = 100 MHz; T_{amb} = 25 °C | [1] | - | 140 | - | MHz |

[1] Characteristics of built-in transistor.



DC current gain as a function of collector current; typical values

Fig. 5. Collector-emitte function of collector

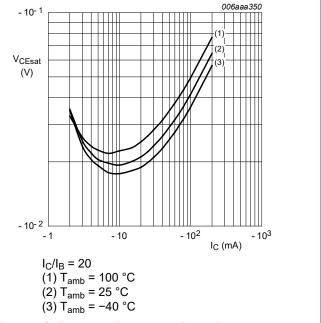
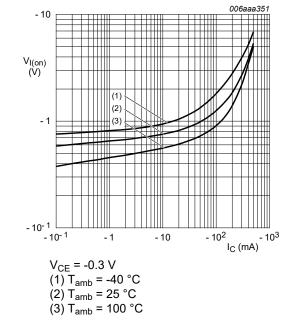


Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values

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On-state input voltage as a function of collector | Fig. 7. Fig. 6. current; typical values

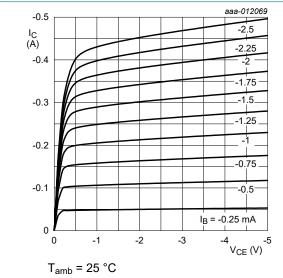
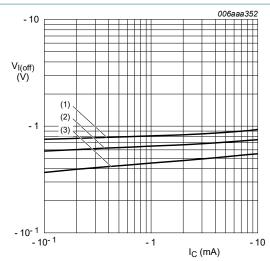
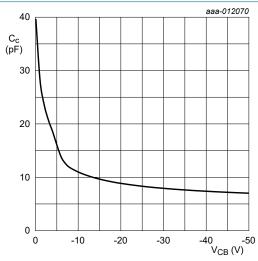


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

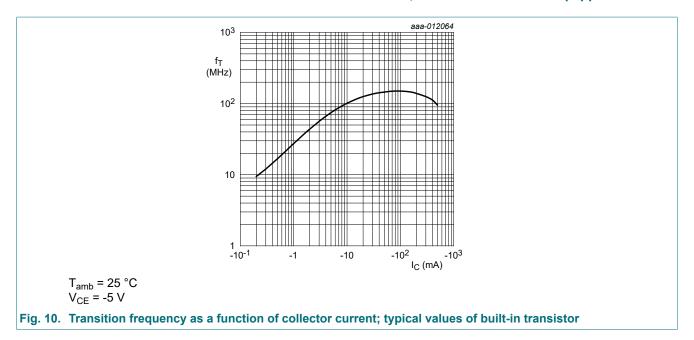
Off-state input voltage as a function of collector current; typical values



f = 1 MHz $T_{amb} = 25 \, ^{\circ}C$

Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

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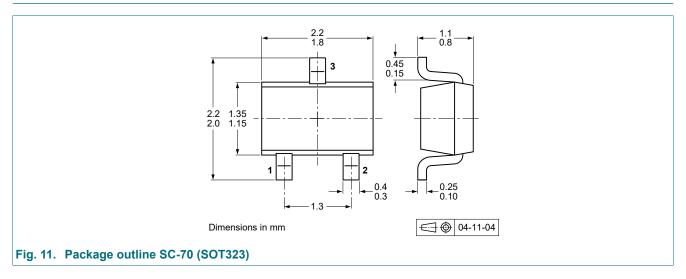


11. Test information

Quality information

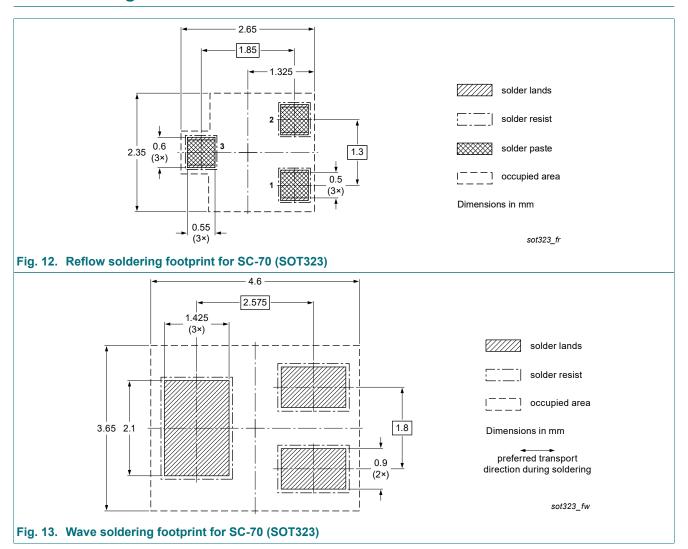
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
|-------------------|--|--------------------|---------------|-------------------|--|--|--|--|
| PDTB113ZU v.2 | 20240408 | Product data sheet | - | PDTB1XXXU_SER v.1 | | | | |
| Modifications: | Family data sheet reduced to single type data sheet. | | | | | | | |
| PDTB1XXXU_SER v.1 | 20140506 | Product data sheet | - | - | | | | |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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